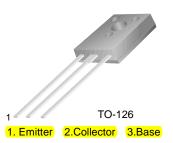


# BD135/137/139

# Medium Power Linear and Switching Applications

• Complement to BD136, BD138 and BD140 respectively



# **NPN Epitaxial Silicon Transistor**

## Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Para	imeter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	: BD135	45	V
		: BD137	60	V
		: BD139	80	V
V <sub>CEO</sub>	Collector-Emitter Voltage	: BD135	45	V
		: BD137	60	V
		: BD139	80	V
V <sub>EBO</sub>	Emitter-Base Voltage		5	V
I <sub>C</sub>	Collector Current (DC)		1.5	A
I <sub>CP</sub>	Collector Current (Pulse)		3.0	A
I <sub>B</sub>	Base Current		0.5	A
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C	C)	12.5	W
P <sub>C</sub>	Collector Dissipation (Ta=25°C	;)	1.25	W
TJ	Junction Temperature		150	°C
T <sub>STG</sub>	Storage Temperature		- 55 ~ 150	°C

## Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

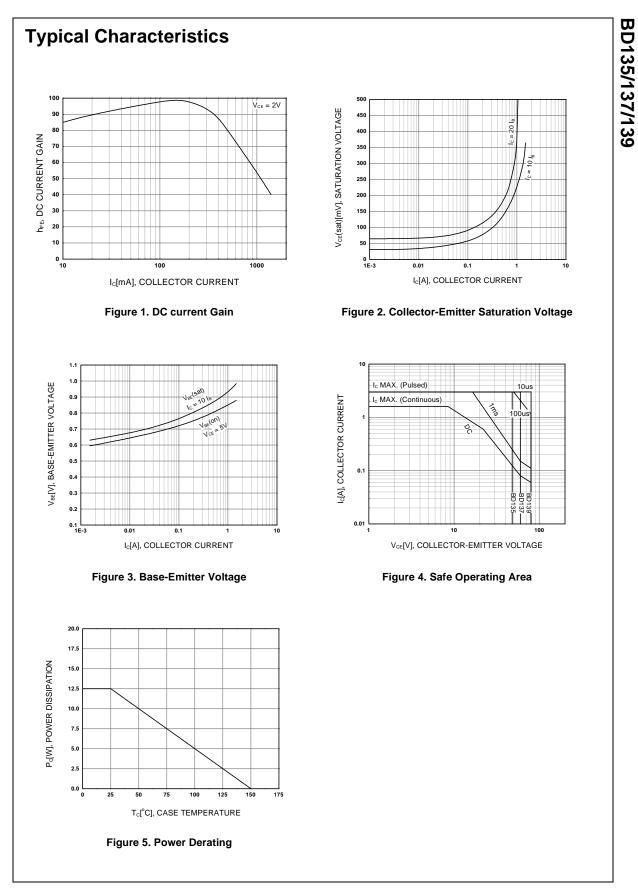
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V <sub>CEO</sub> (sus)	Collector-Emitter Sustaining Voltage					
	: BD135	$I_{\rm C} = 30 {\rm mA}, I_{\rm B} = 0$	45			V
	: BD137		60			V
	: BD139		80			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 30V, I_E = 0$			0.1	μA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			10	μΑ
h <sub>FE1</sub>	DC Current Gain : ALL DEVICE	$V_{CE} = 2V, I_{C} = 5mA$	<mark>25</mark>			
h <sub>FE2</sub>	: ALL DEVICE	$V_{CE} = 2V, I_{C} = 0.5A$	<mark>25</mark>			
h <sub>FE3</sub>	: BD135	$V_{CE} = 2V, I_{C} = 150 \text{mA}$	40		250	
	: BD137, BD139		<mark>40</mark>		<mark>160</mark>	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA			0.5	V
V <sub>BE</sub> (on)	Base-Emitter ON Voltage	$V_{CE} = 2V, I_{C} = 0.5A$			1	V

## h<sub>FE</sub> Classification

Classification	6 10		16
h <sub>FE3</sub>	40 ~ 100	63 ~ 160	100 ~ 250

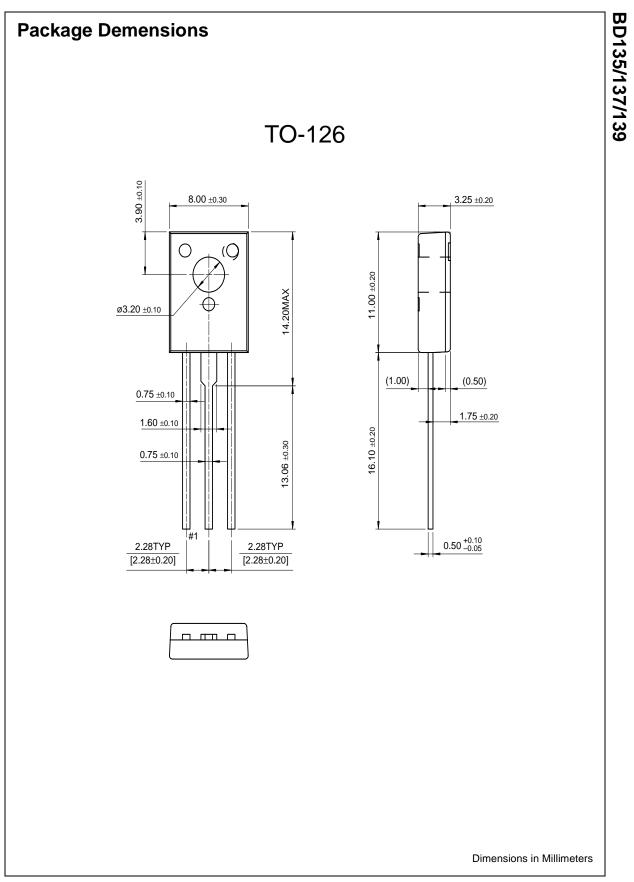
Rev. A, February 2000

BD135/137/139



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